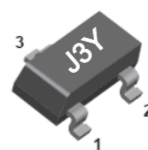


FEATURES

- High Collector Current.($I_C = 500\text{mA}$).
- Complementary To S8550.
- Excellent H_{FE} Linearity.
- High total power dissipation.($P_C = 300\text{mW}$).



SOT-23

APPLICATIONS

- High Collector Current..



MAXIMUM RATING @ $T_a = 25^\circ\text{C}$ unless otherwise specified

| Symbol | Parameter | Value | Units |
|----------------|----------------------------------|-------------|------------------|
| V_{CBO} | Collector-Base Voltage | 40 | V |
| V_{CEO} | Collector-Emitter Voltage | 25 | V |
| V_{EBO} | Emitter-Base Voltage | 5 | V |
| I_C | Collector Current -Continuous | 300 | mA |
| P_C | Collector Dissipation | 300 | mW |
| T_j, T_{stg} | Junction and Storage Temperature | -55 to +150 | $^\circ\text{C}$ |

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

| Parameter | Symbol | Test conditions | MIN | TYP | MAX | UNIT |
|--------------------------------------|---------------|---|-----------|-----|-----|---------|
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_C=100\mu A, I_E=0$ | 40 | | | V |
| Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_C=0.1mA, I_B=0$ | 25 | | | V |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | $I_E=100\mu A, I_C=0$ | 5 | | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}=40V, I_E=0$ | | | 0.1 | μA |
| Collector cut-off current | I_{CEO} | $V_{CE}=20V, I_B=0$ | | | 0.1 | μA |
| Emitter cut-off current | I_{EBO} | $V_{EB}=5V, I_C=0$ | | | 0.1 | μA |
| DC current gain | h_{FE} | $V_{CE}=1V, I_C=50mA$ $V_{CE}=1V, I_C=500mA$ | 120 50 | | 350 | |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C=500mA, I_B=50mA$ | | | 0.6 | V |
| Base-emitter saturation voltage | $V_{BE(sat)}$ | $I_C=500mA, I_B=50mA$ | | | 1.2 | V |
| Transition frequency | f_T | $V_{CE}=6V, I_C=20mA$ $f=30MHz$ | 150 | | | MHz |

CLASSIFICATION OF $h_{FE(1)}$

| Rank | L | H |
|-------|---------|---------|
| Range | 120-200 | 200-350 |

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

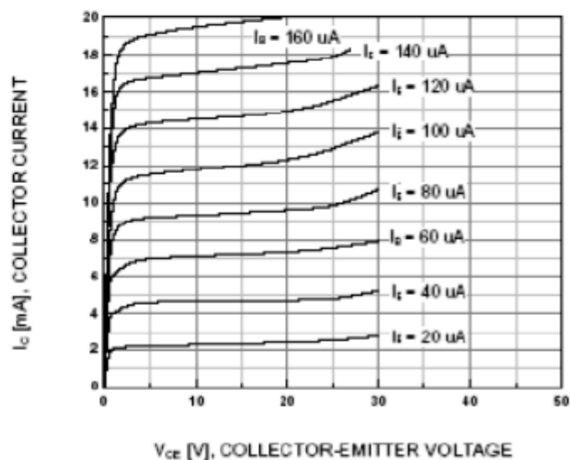


Figure 1. Static Characteristic

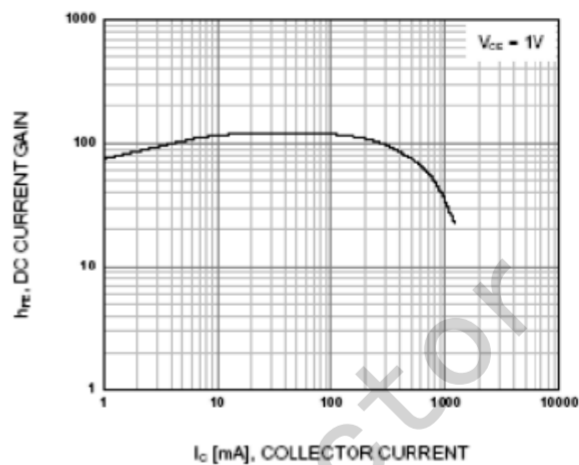
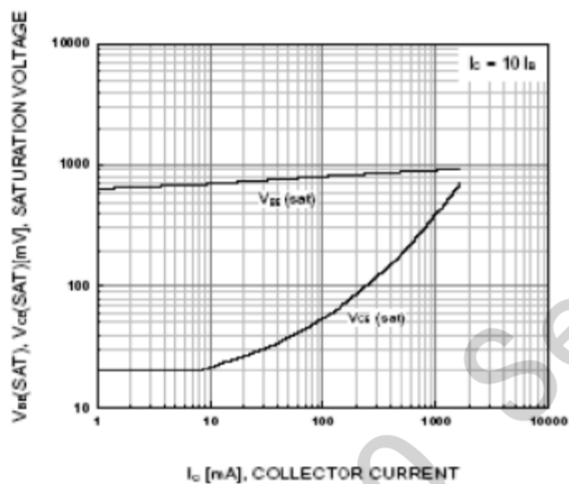


Figure 2. DC current Gain



**Figure 3. Base-Emitter Saturation Voltage
 Collector-Emitter Saturation Voltage**

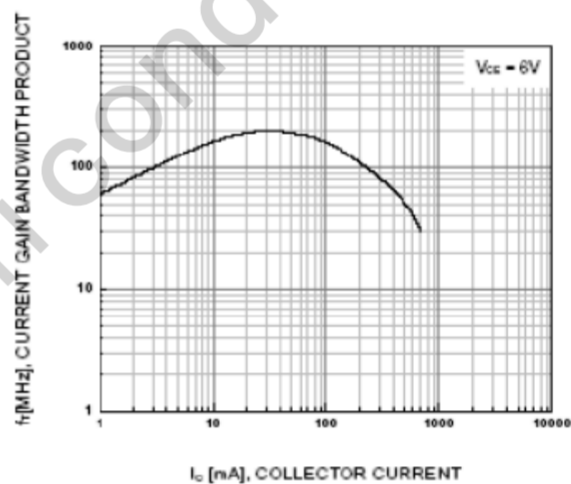
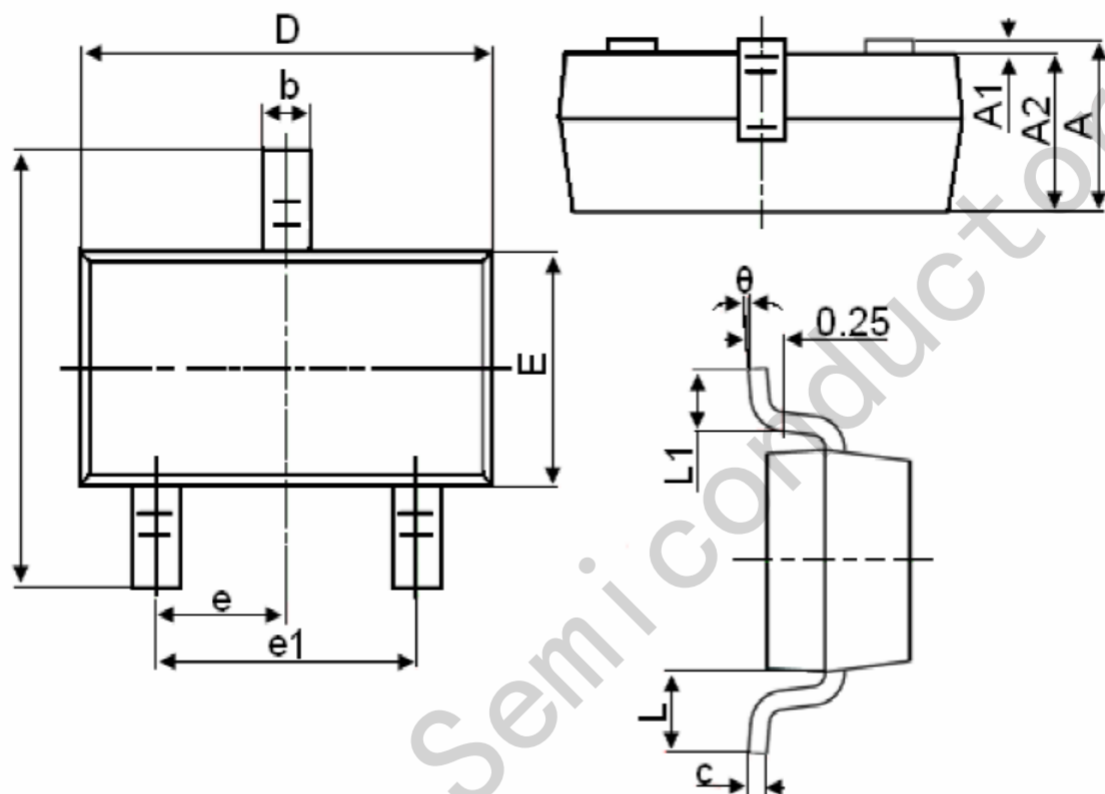


Figure 4. Current Gain Bandwidth Product

Package Information

SOT-23



| Symbol | Dimensions in Millimeters(mm) | | Dimensions In Inches | |
|--------|-------------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 0.900 | 1.150 | 0.035 | 0.045 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.800 | 3.000 | 0.110 | 0.118 |
| E | 1.200 | 1.400 | 0.047 | 0.055 |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 |
| e | 0.950TYP | | 0.037TYP | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.550REF | | 0.022REF | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 |
| theta | 0° | 8° | 0° | 8° |

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Bipolar Transistors - BJT category](#):

Click to view products by [JSMSEMI manufacturer](#):

Other Similar products are found below :

[BC559C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [NJVMJD148T4G](#) [NTE16](#) [NTE195A](#) [IMX9T110](#) [2N4401-A](#) [2N4403](#) [2N6728](#)
[2SA1419T-TD-H](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [FMC5AT148](#) [2N2369ADCSM](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC4618TLN](#) [CPH6501-](#)
[TL-E](#) [MCH4021-TL-E](#) [Jantx2N5416](#) [US6T6TR](#) [BAX18/A52R](#) [BC556/112](#) [IMZ2AT108](#) [MMST8098T146](#) [UMX21NTR](#) [MCH6102-TL-E](#)
[TTA1452B,S4X\(S](#) [2N3879](#) [NTE13](#) [NTE282](#) [NTE323](#) [NTE350](#) [NTE81](#) [JANTX2N2920L](#) [JANTX2N3735](#) [JANSR2N2222AUB](#)
[CMLT3946EG TR](#) [SNSS40600CF8T1G](#) [CMLT3906EG TR](#) [GRP-DATA-JANS2N2907AUB](#) [GRP-DATA-JANS2N2222AUA](#)
[MMDT3946FL3-7](#) [2N4240](#) [JANS2N3019](#) [MSB30KH-13](#) [2N2221AUB](#)